NSN 5961-01-440-7443

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-440-7443 **Inclosure Material:** Plastic **Overall Length:** 0.220 inches **Overall Height:** 0.096 inches **Overall Width:** 0.155 inches **End Application:** 6625-01-416-4444 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-214ab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: